

INCHANGE SEMICONDUCTOR

isc N-Channel MOSFET Transistor

IXTP240N055T

RDS(• Fully ch • 100% a • Minimu perform • APPLIC • DC/DC • High C	drain-source on-resistance: on) ≤ 3.6mΩ@V _{GS} =10V haracterized avalanche voltage and avalanche tested im Lot-to-Lot variations for robust d nance and reliable operation	pin 1, Gate 2, Drain 3, Source TO-220C packag		
SYMBOL	PARAMETER	VALUE	UNIT	
V _{DSS}	Drain-Source Voltage	55	V	
V _{GS}	Gate-Source Voltage	±20	V	K 15,002 V
ID	Drain Current-Continuous	240	А	
I _{DM}	Drain Current-Single Pulsed	650	А	
PD	Total Dissipation @Tc=25°C	480	W	DIM MIN MAX A 15.50 15.90
Tj	Operating Junction Temperature	-55~175	°C	B 9.90 10.20 C 4.20 4.50 D 0.70 0.90
T _{stg}	Storage Temperature	-55~175	°C	F 3.40 3.70 G 4.98 5.18 H 2.68 2.90
• THERM		MAY		J 0.44 0.60 K 13.00 13.40 L 1.10 1.45 Q 2.70 2.90

1

SYMBOL	PARAMETER	MAX	UNIT				
R _{th(j-c)} Junction-to-case thermal resistance		0.31	°C/W				

isc website: www.iscsemi.cn

R

S

U

v

2.30

1.29 6.45 8.66 2.70

6.65

8.86



isc N-Channel MOSFET Transistor

IXTP240N055T

ELECTRICAL CHARACTERISTICS

$T_c=25^{\circ}C$ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	МАХ	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; ID = 250 μ A			V
$V_{GS(th)}$	Gate Threshold Voltage	V _{DS} =V _{GS} ; ID = 250 μ A	2.0	4.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} =10V; I _D = 25A		3.6	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} = ±20V;V _{DS} =0V		±200	nA
I _{DSS}	Drain-Source Leakage Current	V _{DS} = V _{DSS} ; V _{GS} = 0V	5		μA
		V _{DS} = V _{DSS} ; V _{GS} = 0V;T _J = 150°C		250	μA
V_{SD}	Diode forward voltage	I _F = 50A; V _{GS} = 0V		1.2	V

NOTICE:

ISC reserves the rights to make changes of the content herein the datasheet at any time without notification. The information contained herein is presented only as a guide for the applications of our products.

ISC products are intended for usage in general electronic equipment. The products are not designed for use in equipment which require specialized quality and/or reliability, or in equipment which could have applications in hazardous environments, aerospace industry, or medical field. Please contact us if you intend our products to be used in these special applications. ISC makes no warranty or guarantee regarding the suitability of its products for any particular purpose, nor does ISC assume any liability arising from the application or use of any products, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages.